

DISCLAIMER

This document is provided by Soitec (the "Company") for information purposes only.

The Company's business operations and financial position are described in the Company's 2020-2021 Universal Registration Document (which notably includes the 2020-2021 Annual Financial Report).

The Company's 2020-2021 Universal Registration Document was filed with the AMF. The Universal Registration Document is available on the Company's website in both French and English versions (www. soitec.com, in section "Company -Investors - Financial Reports"). Your attention is drawn to the risk factors described in Chapter 2.1 of the Company's 2020-2021 Universal Registration Document.

This document contains summary information and should be read in conjunction with the 2020-2021 Universal Registration Document.

This document contains certain forward-looking statements. These forward-looking statements relate to the Company's future prospects, developments and strategy and are based on analyses of earnings forecasts and estimates of amounts not yet determinable. By their nature, forward-looking statements are subject to a variety of risks and uncertainties as they relate to future events

and are dependent on circumstances that may or may not materialize in the future. Forward-looking statements are not a guarantee of the Company's future performance.

The Company's actual financial position, results and cash flows, as well as the trends in the sector in which the Company operates may differ materially from those contained in this document. Furthermore, even if the Company's financial position, results, cash-flows and the developments in the sector in which the Company operates were to conform to the forward-looking statements contained in this document, such elements cannot be construed as a reliable

indication of the Company's future results or developments.

The Company does not undertake any obligation to update or make any correction to any forward-looking statement in order to reflect an event or circumstance that may occur after the date of this document. In addition, the occurrence of any of the risks described in Chapter 2.1 of the Universal Registration Document may have an impact on these forward-looking statements.

This document does not constitute or form part of an offer or a solicitation to purchase, subscribe for, or sell the Company's securities in any country whatsoever. This document, or any part thereof,

shall not form the basis of, or be relied upon in connection with, any contract, commitment or investment decision.

Notably, this document does not constitute an offer or solicitation to purchase, subscribe for or to sell securities in the United States. Securities may not be offered or sold in the United States absent registration or an exemption from the registration under the U.S. Securities Act of 1933, as amended (the "Securities Act"). The Company's shares have not been and will not be registered under the Securities Act. Neither the Company nor any other person intends to conduct a public offering of the Company's securities in the United States.



SOITEC AT A GLANCE

FOCUSING ON 3 STRATEGIC MARKETS TO EXPAND OUR PRODUCTS

PORTFOLIO

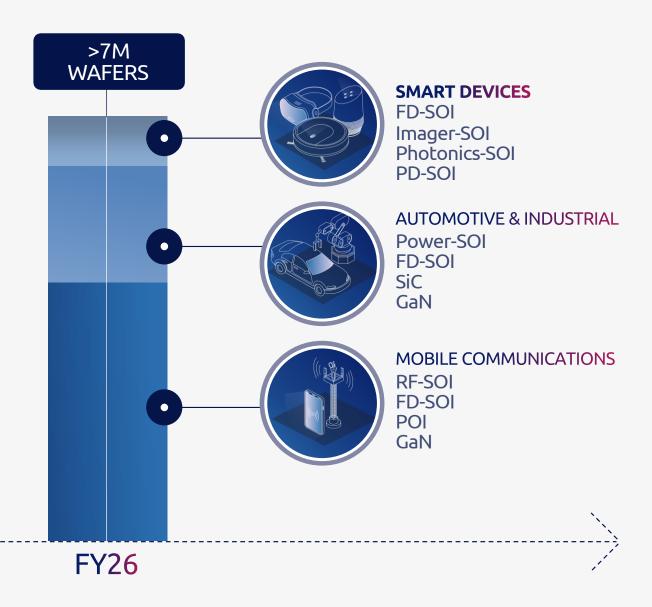




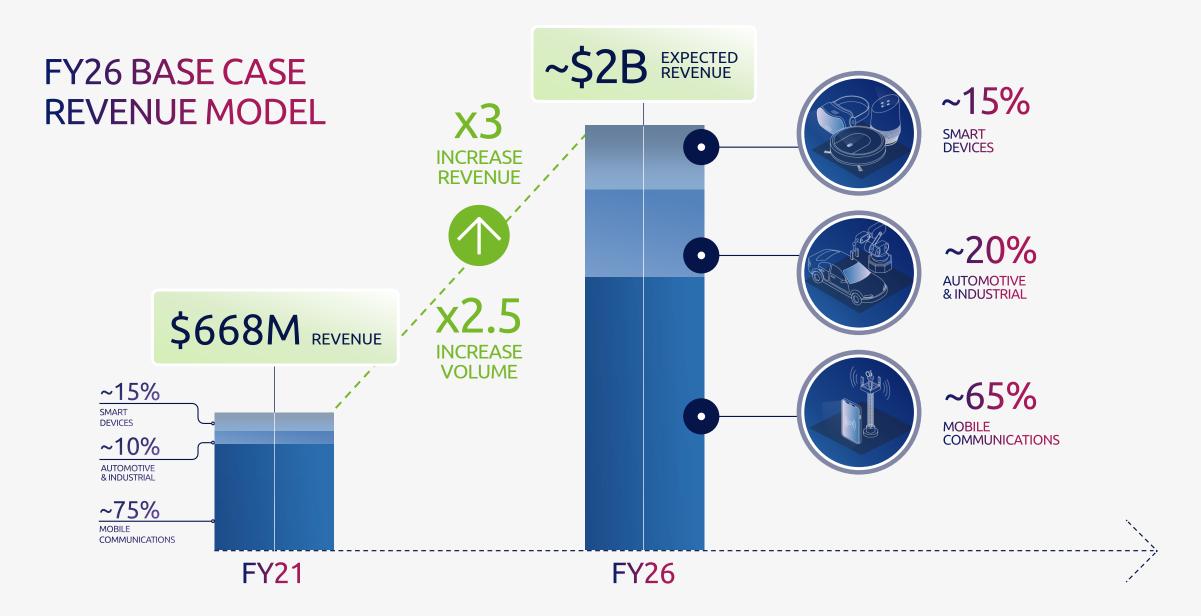


SERVING > 7 MILLION WAFERS ADDRESSABLE MARKET* BY FY26



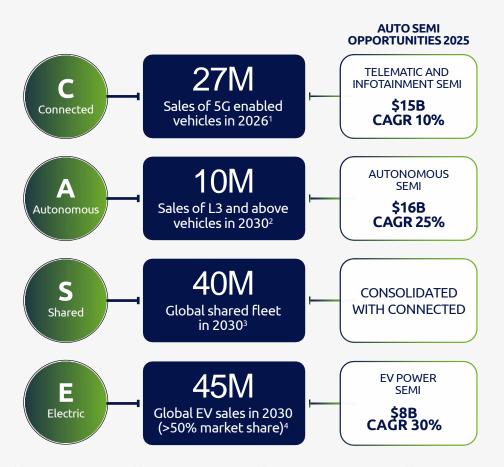


^{*}Engineered substrates market opportunity



AUTOMOTIVE & INDUSTRIAL

ONCE-IN-A CENTURY TRANSFORMATION IN AUTOMOTIVE MARKET







SIC IS KEY TO ADDRESS THE CHALLENGES OF EV ADOPTION



Range

anxiety





Thermal conductivity





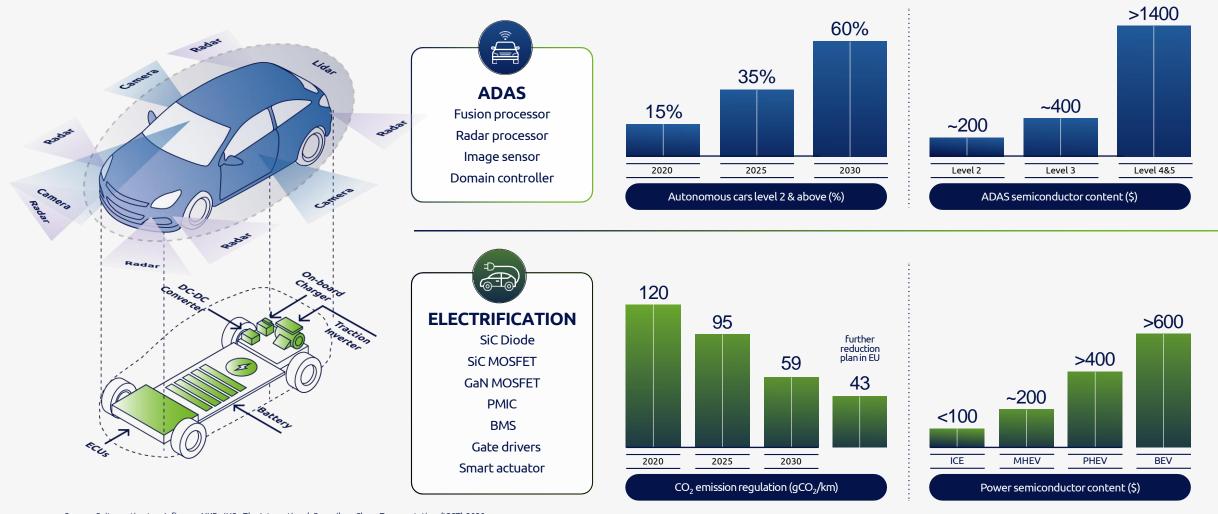


Charging time

Cost

(1) v.s. 2020: Zero 5G vehicles; (2) v.s. 2020: Zero L3+ vehicles; (3) v.s. 2020: 19m global shared fleet; (4) v.s. 2020: 3.2m EV sales: 4.2% market share Sources: Soitec estimates, LMC, IHS, NXP, IFX 2019 / CAGR (2019~2025), IEA 2021, Exawatt, Yole.

AUTOMOTIVE MEGATRENDS DRIVE INNOVATION FROM SYSTEMS TO SILICON



Source: Soitec estimates, Infineon, NXP, IHS, The International Council on Clean Transportation (ICCT) 2020

SOITEC PRODUCTS PORTFOLIO AUTOMOTIVE & INDUSTRIAL

APPLICATIONS

- Autonomous driving systems
- Connected car
- Vehicle electrification
- Industry 4.0



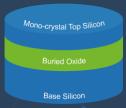
SOITEC PRODUCTS ENABLE

- Autonomous driving
- Infotainment
- Vehicle electrification



Power-SOI

Power management ICs, In-vehicle networking & gate drivers



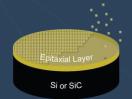
FD-SOI

MCUs, ADAS-Radars ADAS-Vision



GaN

DC-DC 48V converters



Smart Cut™ SiC

Automotive electrification





COMPREHENSIVE PRODUCTS PORTFOLIO FOR AUTOMOTIVE



INFOTAINMENT & CONNECTIVITY

Class D audio amplifier (Power-SOI)

Multimedia application processor (FD-SOI)

IVN (Power-SOI)

Front-end module (RF-SOI / POI)

SoC (FD-SOI)



ADAS

Vision processor (FD-SOI) Radar

(FD-SOI)

Domain controller (FD-SOI)



POWERTRAIN

Gate drivers / actuator (Power-SOI) Diode / MOSFET

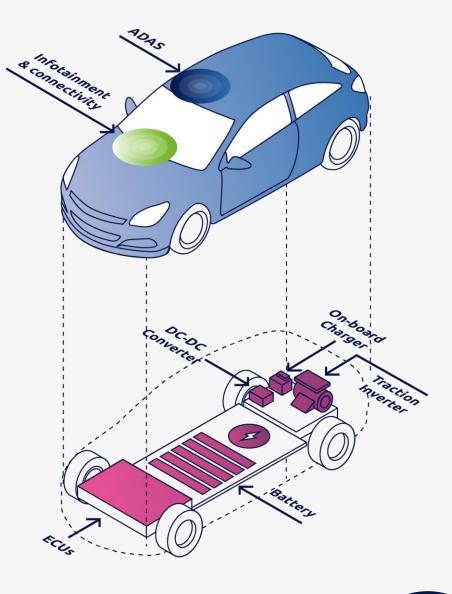
Diode / MOSFET (SiC / GaN Power)

BMS

(Power-SOI)

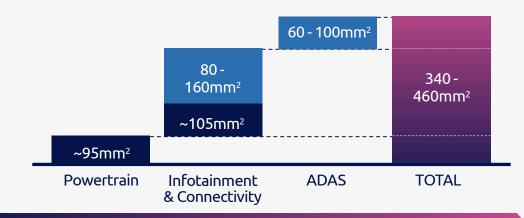
PMIC

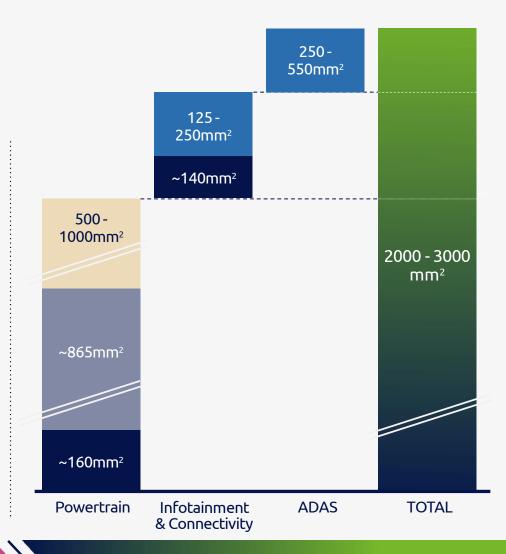
(Power-SOI)



AUTOMOTIVE CONTENT OPPORTUNITY IN THE NEXT FIVE YEARS IN mm²

- Power-SOI
- FD-SOI
- Smart Cut™ SiC
- GaN





TODAY

WITHIN THE NEXT 5 YEARS

SMART CUTTM SiC

Smart CutTM SiC





EXISTING AND FUTURE APPLICATIONS

- Electric mobility
- On-board chargers
- Traction inverter system
- Fast charging stations
- Inverters: industrial, renewable energy

VALUE PROPOSITION

Smart Cut™ SiC vs SiC: It is all about device yield and performances!

- Strong reduction of defect density (x5) to enable larger die
- Lower resistivity substrate improves device power performance
- 200mm scalability to accelerate SiC adoption

FAMILY "SMART CUT SIC PRODUCT" ROADMAP FROM FY23

200mm Low resistivity Smart Cut™ SiC

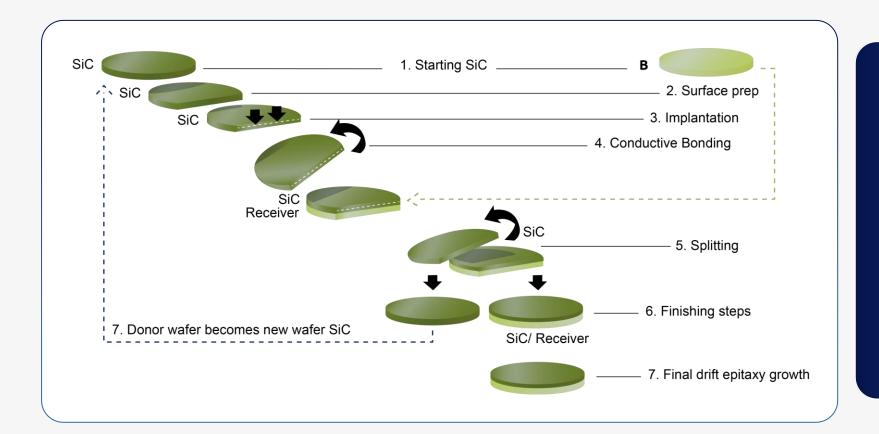
150mm Low resistivity Smart Cut™ SiC

150mm Smart Cut™ SiC

Timeline



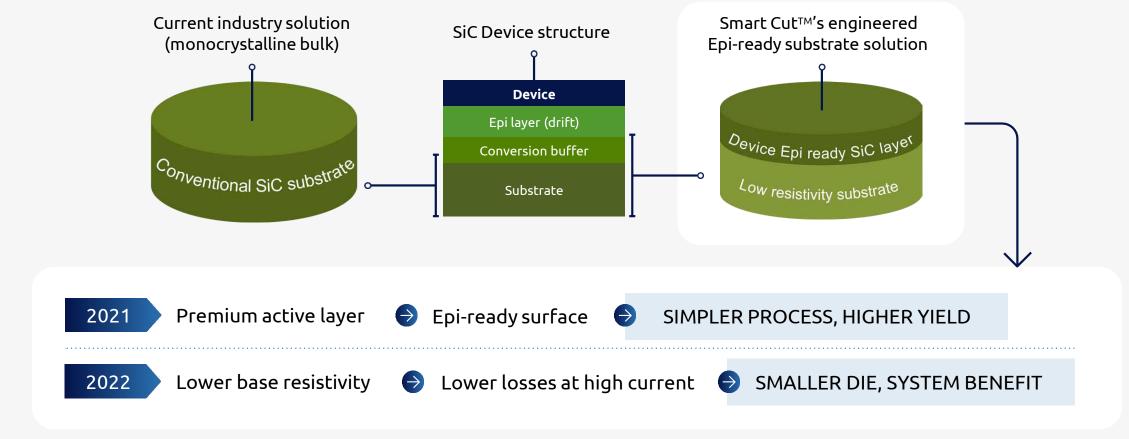
SMART CUTTM PROCESS ADAPTED TO SIC FULL R&D PILOT LINE RUNNING



MAJOR STAGES OF SMART CUT™ SiC

- Donor wafer: Prime quality SiC
- Handle wafer: Low Res SiC
- Conductive bonding interface
- Finishing including CMP & high temp anneal
- Donor wafer re-use for new process cycle

SMART CUTTM SOLUTION SIC ENGINEERED SUBSTRATE



A GREENER SIC WAFER WITH SMART CUTTM TECHNOLOGY

Low environmental impact driven by...



Improved **RE-USABILITY**



Lower DIE SIZE



Higher **YIELD**



6-INCH ENGINEERED SIC SUBSTRATE



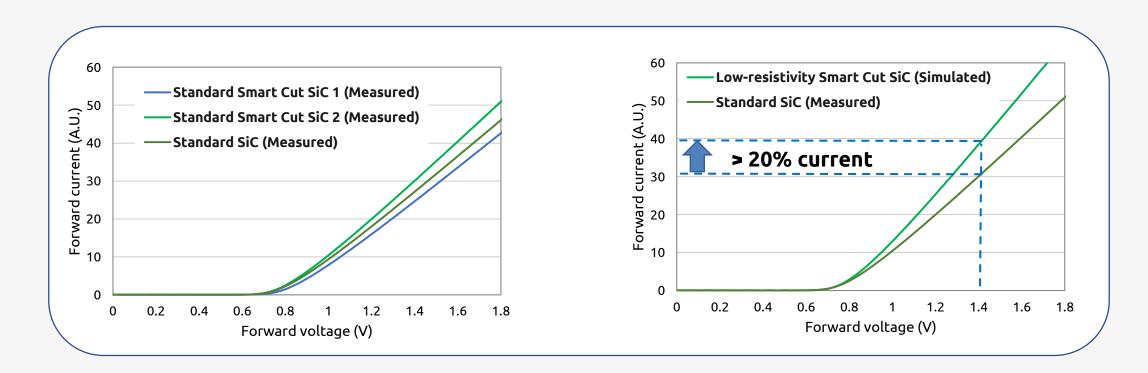








SMART CUTTM SiC DELIVERS SUPERIOR DEVICE PERFORMANCE

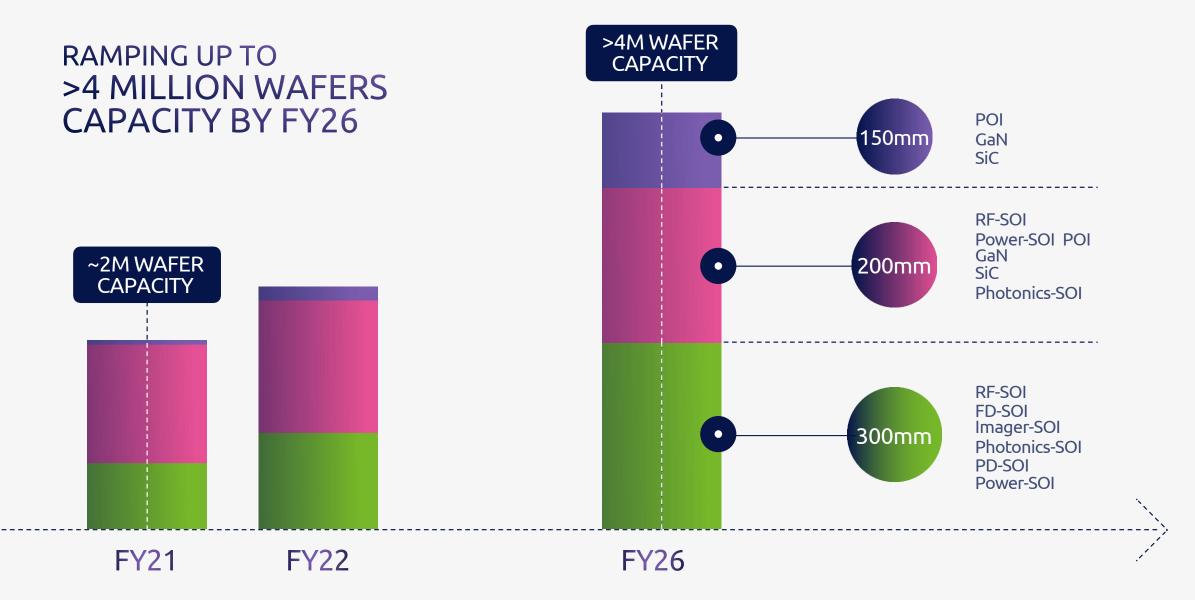


Fully compatible with Schottky diode processing

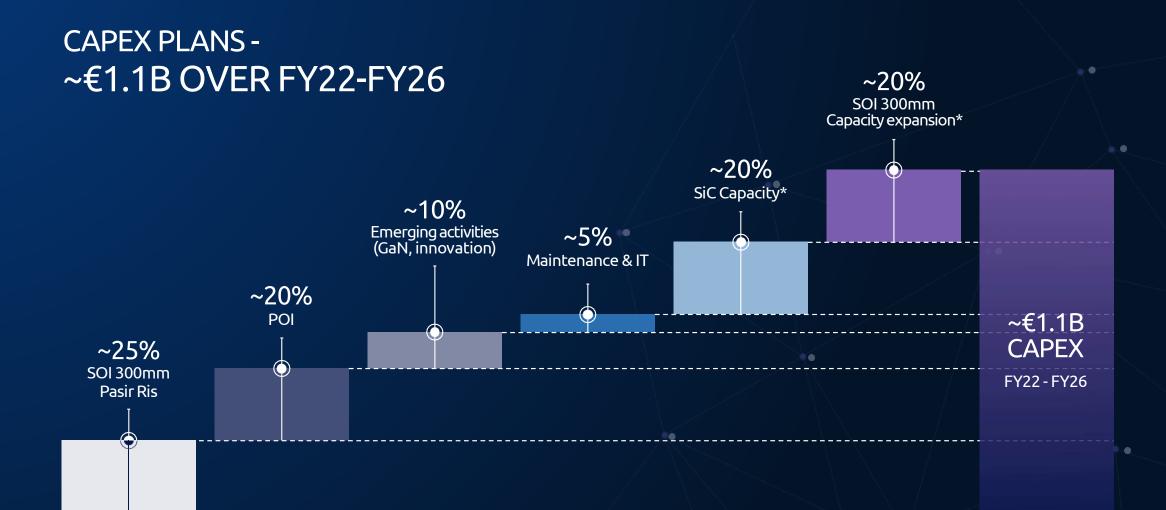
Current gain up to 20% compared to standard SiC

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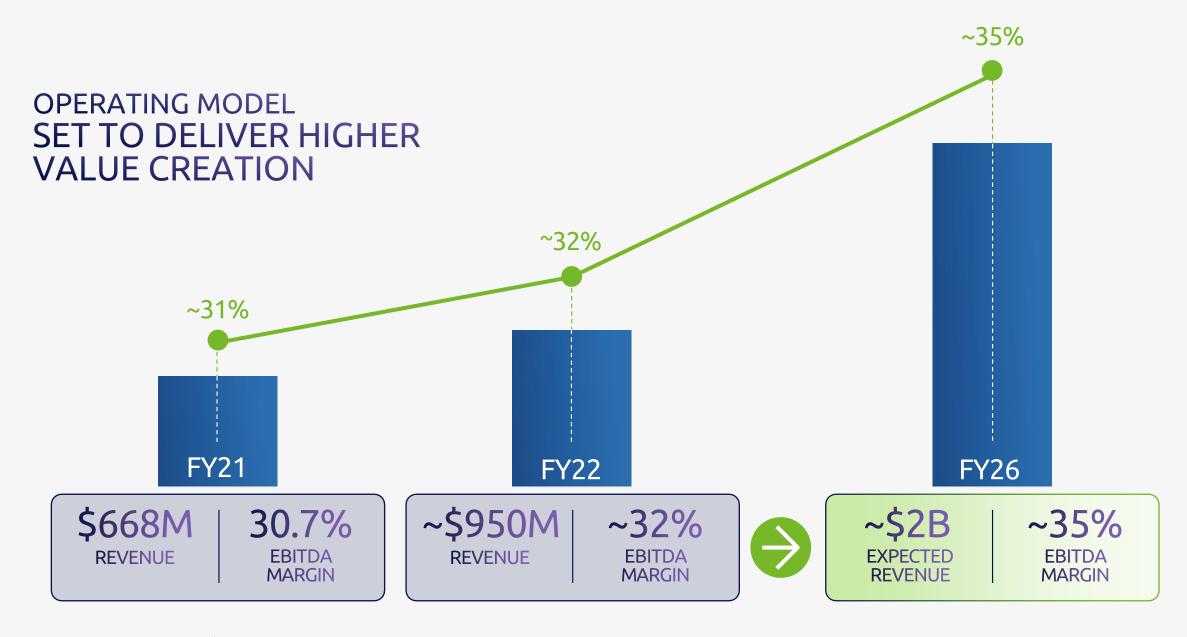
APPENDIX













MID-TERM FINANCIAL MODEL

REVENUE

 Revenue will more than triple between FY21 and FY26 to reach \$2B

PROFITABILITY (@1.20 FX RATE)

- EBITDA in value more than x3 between FY21 and FY26
- CAPEX: around €1.1B between FY22 and FY26*

FINANCING

 Sufficient cumulative operating cash flows to finance CAPEX

	FY21 (Actual)	FY22	FY26 (Model)
FX rate	@1.13	@1.20	@1.20
Revenue (\$M)	668	~950	~2,000
Revenue (€M)	584	~800	~1,700
Gross margin %	31.4%	~34%	~36%
EBITDA % Revenue	30.7%	~32%	~35%
CAPEX % Revenue	24%	~30%	~18% over FY22-26

